TOSHIBA Power Transistor Module Silicon NPN Epitaxial Type (Darlington power transistor 4 in 1)

# **MP4024**

High Power Switching Applications.

Hammer Drive, Pulse Motor Drive and Inductive Load Switching.

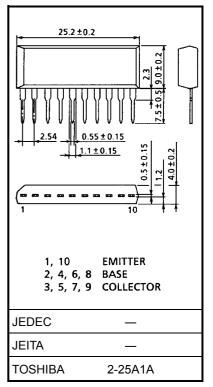
- Small package by full molding (SIP 10 pin)
- Built-in resistance (RB).
- Surge voltage is clamped by zener diode (C-B).
- Low  $V_{CE (sat)}$ :  $V_{CE (sat)} = 1.5 \text{ V (max)}$  ( $I_{C} = 1 \text{ A}$ ,  $V_{BH} = 4.2 \text{ V}$ )
- High DC current gain:  $h_{FE} = 2000$  (min) ( $V_{CE} = 2 \text{ V}$ ,  $I_{C} = 1 \text{ A}$ )

#### Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		$V_{CBO}$	85	V	
Collector-emitter voltage		V <sub>CEO</sub>	100 ± 15	V	
Emitter-base voltage		V <sub>EBO</sub>	6	V	
Input voltage		V <sub>B</sub>	20	V	
Collector current	DC	IC	3	Α	
	Pulse	I <sub>CP</sub>	4		
Collector power dissipation		P <sub>C</sub>	2.0	W	
(1 device operation)			2.0		
Collector power dissipation		P <sub>T</sub>	4.0	W	
(4 devices operation)			4.0	VV	
Junction temperature		Tj	150	°C	
Storage temperature range		T <sub>stg</sub>	−55 to 150	°C	

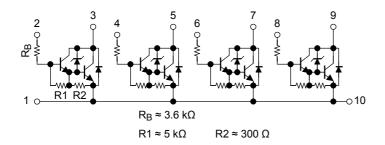
#### **Industrial Applications**

Unit: mm



Weight: 2.1 g (typ.)

#### **Array Configuration**



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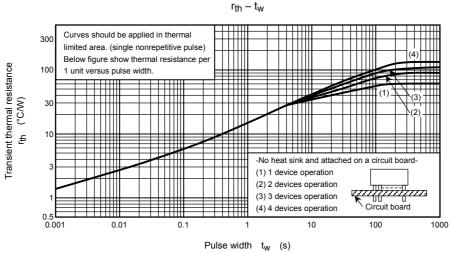
### **Thermal Characteristics**

Characteristics	Symbol	Max	Unit	
Thermal resistance of junction to ambient	ΣR <sub>th (j-a)</sub>	31.3	°C/W	
(4 devices operation, Ta = 25°C)	,			
Maximum lead temperature for soldering purposes	TL	260	ů	
(3.2 mm from case for 10 s)				

## Electrical Characteristics (Ta = 25°C)

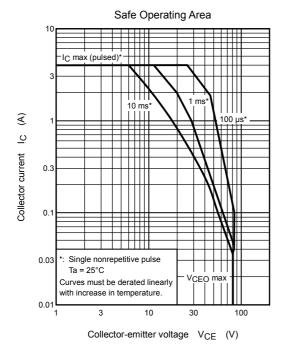
Charac	cteristics	Symbol	Test Condition	Min	Тур.	Max	Unit	
Collector cut-off current		I <sub>CBO</sub>	V <sub>CB</sub> = 80 V, I <sub>E</sub> = 0 A	_	_	10	μΑ	
Collector cut-off current		I <sub>CEO</sub>	V <sub>CE</sub> = 80 V, I <sub>B</sub> = 0 A	_	_	10	μΑ	
Emitter cut-off current		I <sub>EBO</sub>	V <sub>EB</sub> = 6 V, I <sub>C</sub> = 0 A	0.3	_	1.5	mA	
Collector- emitter breakdown voltage		V (BR) CEO	I <sub>C</sub> = 10 mA, I <sub>B</sub> = 0 A	85	100	115	V	
Resistance		R <sub>B</sub>	_	2.5	3.6	4.7	kΩ	
DC current gain		h <sub>FE (1)</sub>	V <sub>CE</sub> = 2 V, I <sub>C</sub> = 1 A	2000	_	_		
		h <sub>FE (2)</sub>	V <sub>CE</sub> = 2 V, I <sub>C</sub> = 2 A	1000	_	_	_	
Collector-emitter saturation voltage		V <sub>CE</sub> (sat) (1)	I <sub>C</sub> = 1 A, V <sub>BH</sub> = 4.2 V	_	_	1.5	V	
		V <sub>CE</sub> (sat) (2)	I <sub>C</sub> = 1.5 A, V <sub>BH</sub> = 9 V	_	_	1.5	v	
Input voltage (low)		V <sub>BL</sub>	V <sub>CE</sub> = 50 V, I <sub>C</sub> = 100 μA	_	_	0.7	V	
Switching time S	Turn-on time	t <sub>on</sub>	Input $20 \mu s$ $0 \text{ V}_{BH} = 5 \text{ V}$ $0 \text{ V}_{CC} = 30 \text{ V}$ Duty cycle $\leq 1\%$	_	0.3	_		
	Storage time	t <sub>stg</sub>			4.0		μs	
	Fall time	t <sub>f</sub>		_	0.6	_		

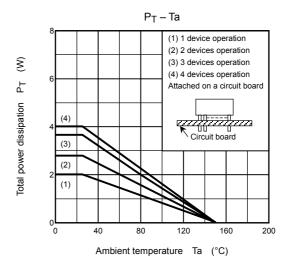
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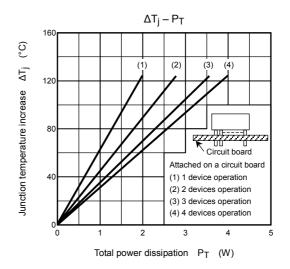




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